

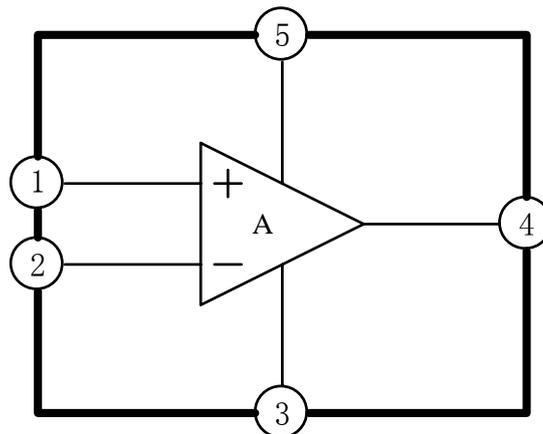
1. Overview

The V2030D is a monolithic IC intended for use as an audio amplifier or a driver circuit. It is particularly suited for audio amplifier without regulated supply, and also for driver circuits. With $V_{CC} = 44V$, using a few external components and low-cost complementary pairs, it can compose a 35W power amplifier. Its **features** are:

- High output current
- Low total harmonic distortion
- Incorporates a short circuit protection system
- Automatically limits the dissipated power so as to keep the working point of the output transistors within their safe operating area.
- Built-in thermal shut-down system
- FZIP5

2. Block Diagram and Pin Description

2.1 Block Diagram



2.2 Pin Description

Pin No.	Symbol	Description	Pin No.	Symbol	Description
1	IN	Signal Input	4	OUT	Output
2	NF	Negative feedback	5	V_{CC}	$+V_{EE}$
3	V_{EE}/GND	$V_{EE}/Ground$			

3. Electrical Characteristics

3.1 Absolute Maximum Ratings

Unless otherwise specified, $T_{amb} = 25^{\circ}C$

Parameter	Symbol	Test Conditions	Value	Unit
Supply Voltage	V_{CC}		± 22	V
Input Voltage	V_{in}		V_{CC}	V
Differential Input Voltage	V_{ind}		± 15	V
Peak Output Current	I_{OP}		3.5	A

Power Dissipation	P_D	$T_C = 90^\circ\text{C}$	20	W
Operating Temperature	T_{amb}		-20 ~ 70	$^\circ\text{C}$
Storage Temperature	T_{stg}		-40 ~ 150	$^\circ\text{C}$

3. 2 Electrical Characteristics

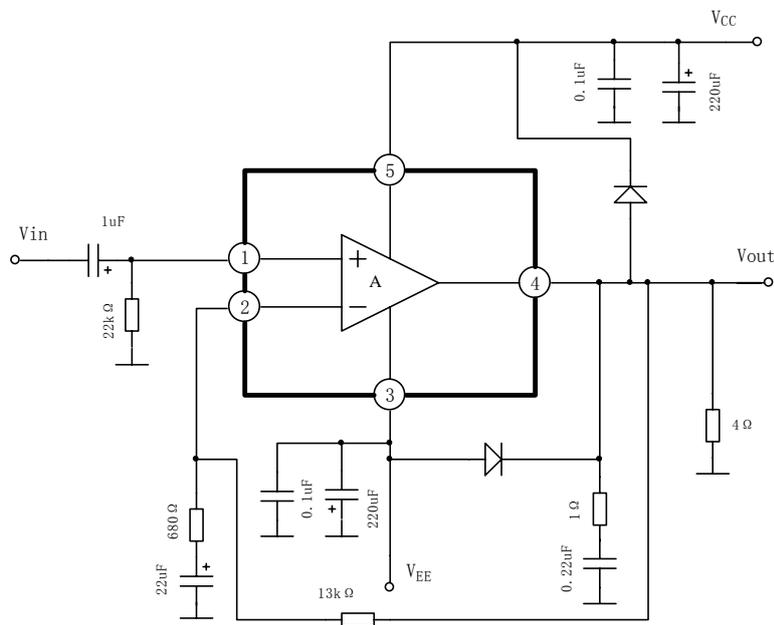
Unless otherwise specified, refer to the test circuit, $T_{\text{amb}} = 25^\circ\text{C}$, $V_{\text{CC}} = \pm 16\text{V}$

Parameter	Symbol	Test Conditions	Value			Unit
			Min	Typ	Max	
Supply Voltage	V_{CC}		± 6		± 22	V
Quiescent Drain Current	I_{CCQ}			50	80	mA
Input Bias Current	I_B	$V_{\text{CC}} = \pm 22\text{V}$		0.2	2	μA
Input Offset Voltage	V_{OS}	$V_{\text{CC}} = \pm 22\text{V}$		2	20	mV
Input Offset Current	I_{OS}			20	200	nA
Output Power	P_O	THD = 0.5%, $A_V = 26\text{dB}$, $f = 40\text{Hz} \sim 15\text{kHz}$				W
		$R_L = 4\ \Omega$	15	18		
		$R_L = 8\ \Omega$	10	12		
		$V_{\text{CC}} = \pm 19\text{V}$, $R_L = 8\ \Omega$	13	16		
Bandwidth	BW	$P_O = 15\text{W}$, $R_L = 4\ \Omega$		100		kHz
Slew Rate	SR			8		V/ μS
Open Loop Voltage Gain	A_{VO}	$f = 1\text{kHz}$		80		dB
Closed Loop Voltage Gain	A_V	$f = 1\text{kHz}$	25.5	26	26.5	dB
Total Harmonic Distortion	THD	$f = 40\text{Hz} \sim 15\text{kHz}$ $P_O = 0.1 \sim 14\text{W}$, $R_L = 4\ \Omega$		0.08		%
		$f = 1\text{kHz}$		0.03		
		$P_O = 0.1 \sim 9\text{W}$, $R_L = 8\ \Omega$ $f = 40\text{Hz} \sim 15\text{kHz}$		0.5		
Second Order CCIF Intermodulation	THD ₂	$P_O = 4\text{W}$, $f_2 - f_1 = 1\text{kHz}$ $R_L = 4\ \Omega$		0.03		%
Third Order CCIF Intermodulation	THD ₃	$f_1 = 14\text{kHz}$ $f_2 = 15\text{kHz}$, $2f_1 - f_2 = 13\text{kHz}$		0.08		%
Input Noise Voltage	V_{ino}	B = Curve A		2		μV
		B = 22Hz~22kHz		3	10	
Input Noise Current	I_{ino}	B = Curve A		50		pA
		B = 22Hz ~ 22kHz		80	200	
Signal to Noise Ratio	S/N	$R_L = 4\ \Omega$, B = Curve A, $R_g = 10\ \text{k}\Omega$				dB
		$P_O = 15\text{W}$		106		
		$P_O = 1\text{W}$		94		
Input Resistance	R_I	$f = 1\text{kHz}$	0.5	5		M Ω
Supply Voltage Rejection	R.R	$R_L = 4\ \Omega$, $R_g = 22\ \text{k}\Omega$ $A_V = 26\text{dB}$, $f = 100\text{Hz}$		54		dB
Thermal Shut-down Junction Temperature	T_j			145		$^\circ\text{C}$

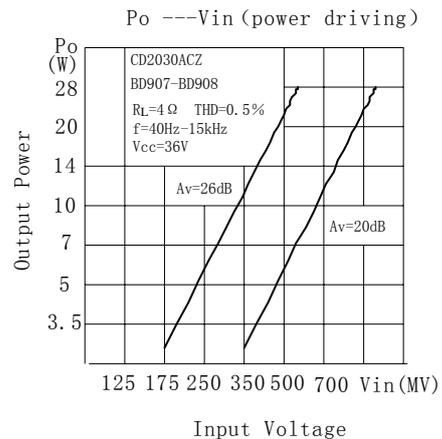
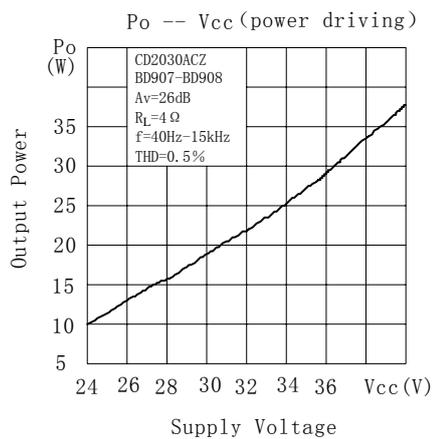
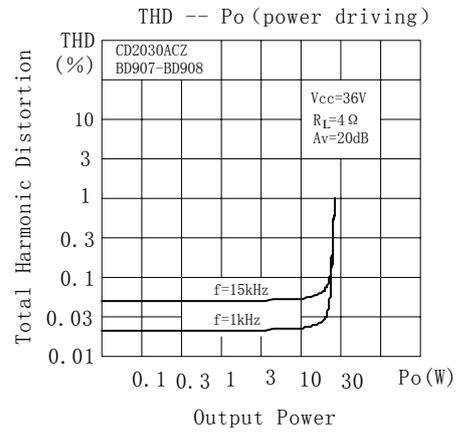
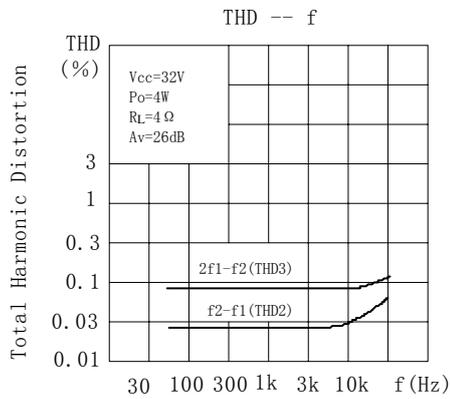
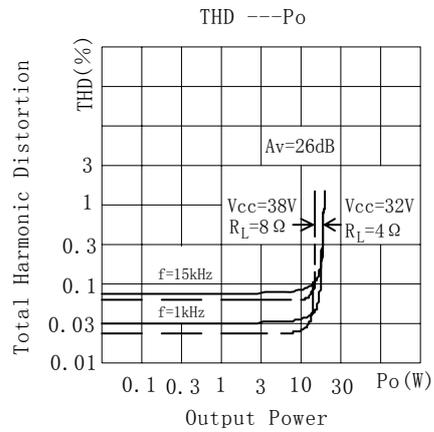
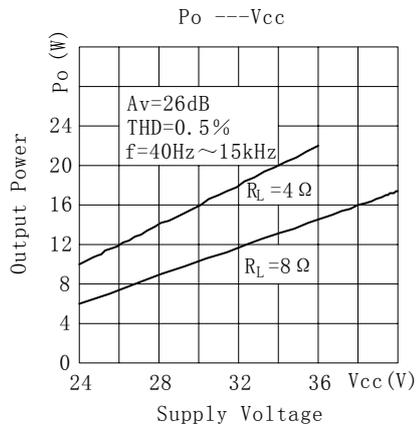
3.3 Typical Performance of the Diver Circuit

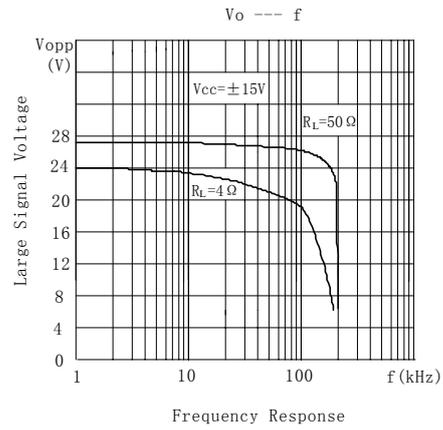
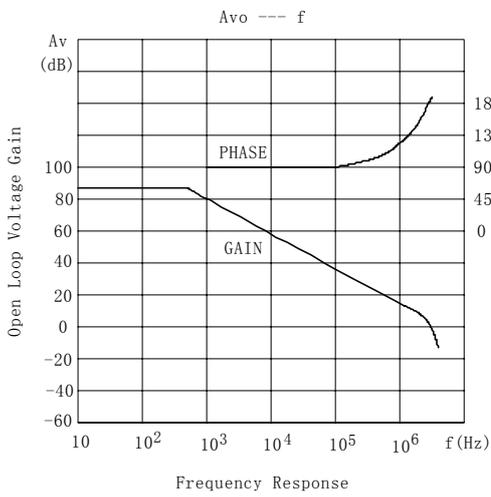
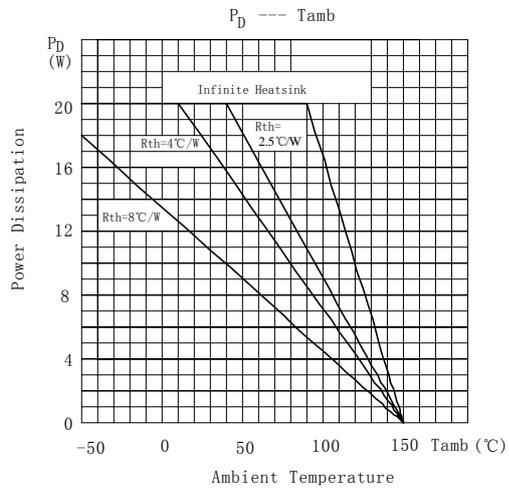
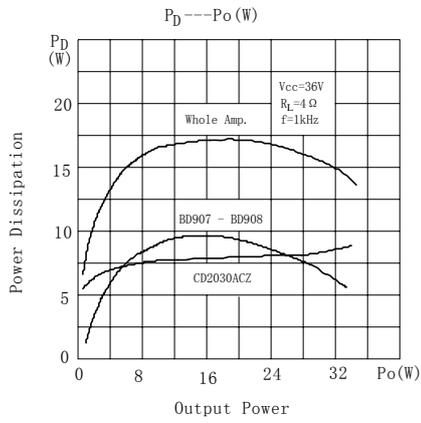
Parameter	Symbol	Test Conditions	Value			Unit
			Min	Typ	Max	
Supply Voltage	V_{CC}			36	44	V
Quiescent Current	I_{CCQ}	$V_{CC} = 36V$		50		mA
Output Power	P_O	THD = 0.5%, $R_L = 4 \Omega$, $f = 40Hz \sim 15kHz$				W
		$V_{CC} = 39V$		35		
		$V_{CC} = 36V$		28		
		THD = 10%, $R_L = 4 \Omega$, $f = 1kHz$				
		$V_{CC} = 39V$		44		
		$V_{CC} = 36V$		35		
Closed Loop Voltage Gain	A_V	$f = 1kHz$	19.5	20	20.5	dB
Slew Rate	SR			8		V/uS
Total Harmonic Distortion	THD	$f = 1kHz, P_O = 20W$		0.02		%
		$f = 40Hz \sim 15kHz, P_O = 20W$		0.05		
Input Sensitivity	V_i	$A_V = 20dB, f = 1kHz, P_O = 20W, R_L = 4 \Omega$		890		mV
Signal to Noise Ratio	S/N	$R_L = 4 \Omega, R_g = 10k \Omega, B = \text{Curve A}$				dB
		$P_O = 25W$		108		
		$P_O = 4W$		100		

4. Test Circuit



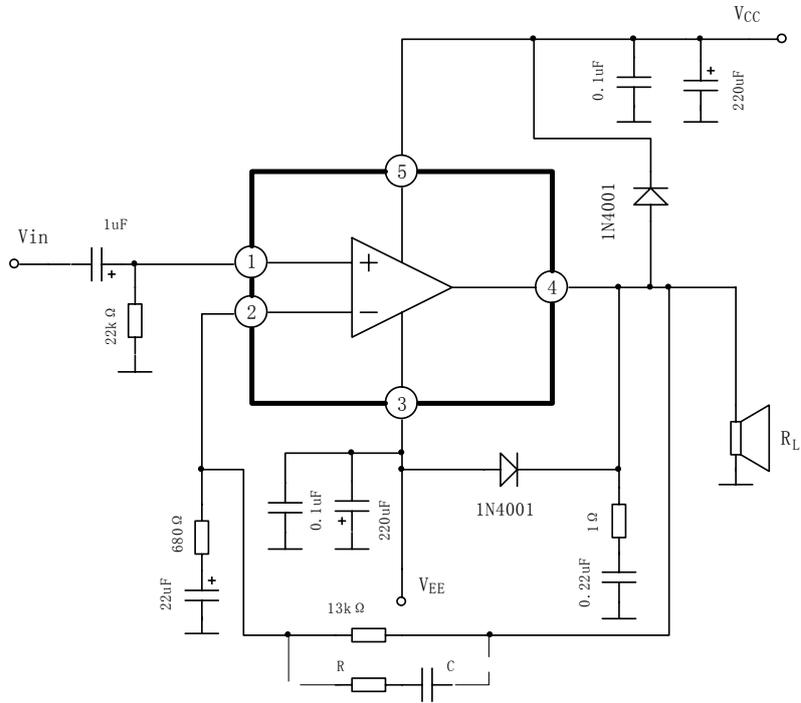
5.Characteristics Curve



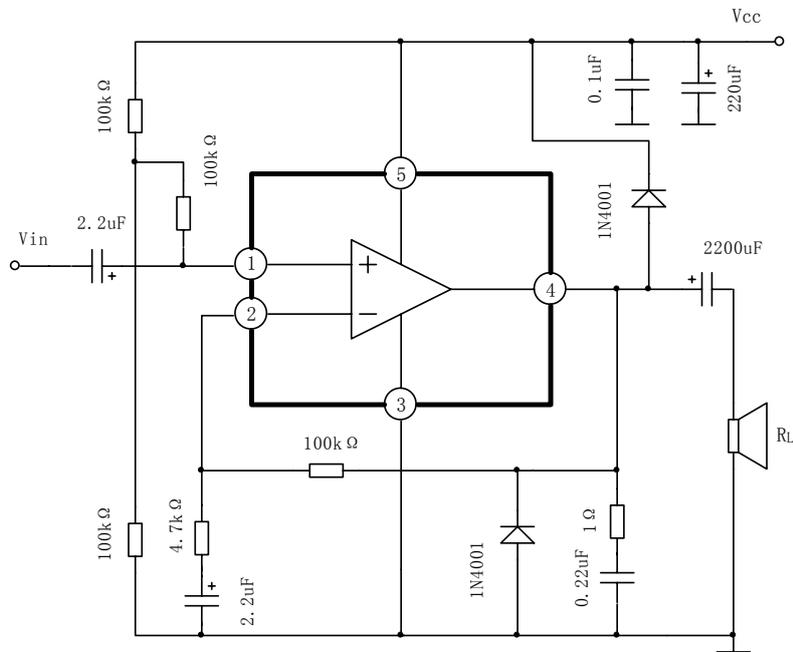


6. Application Circuit

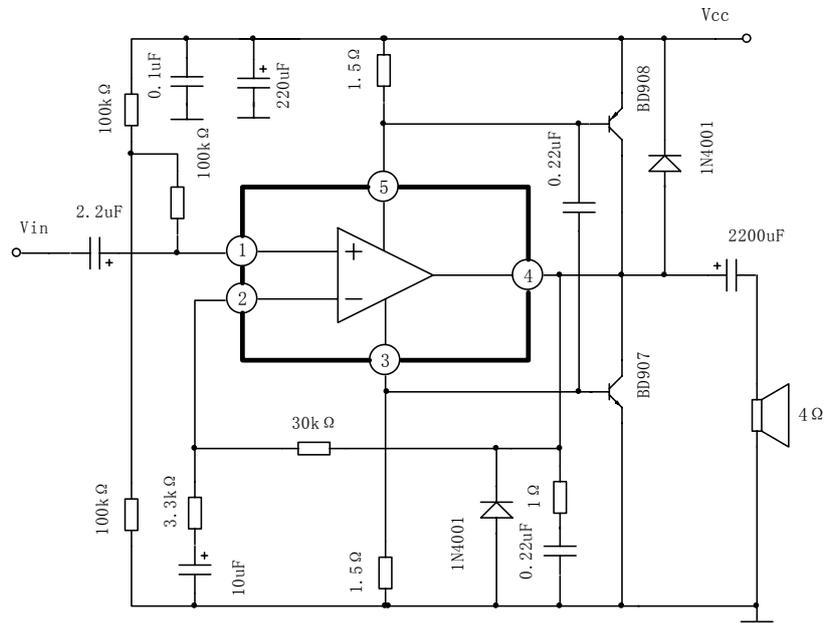
6.1 Typical Application Circuit



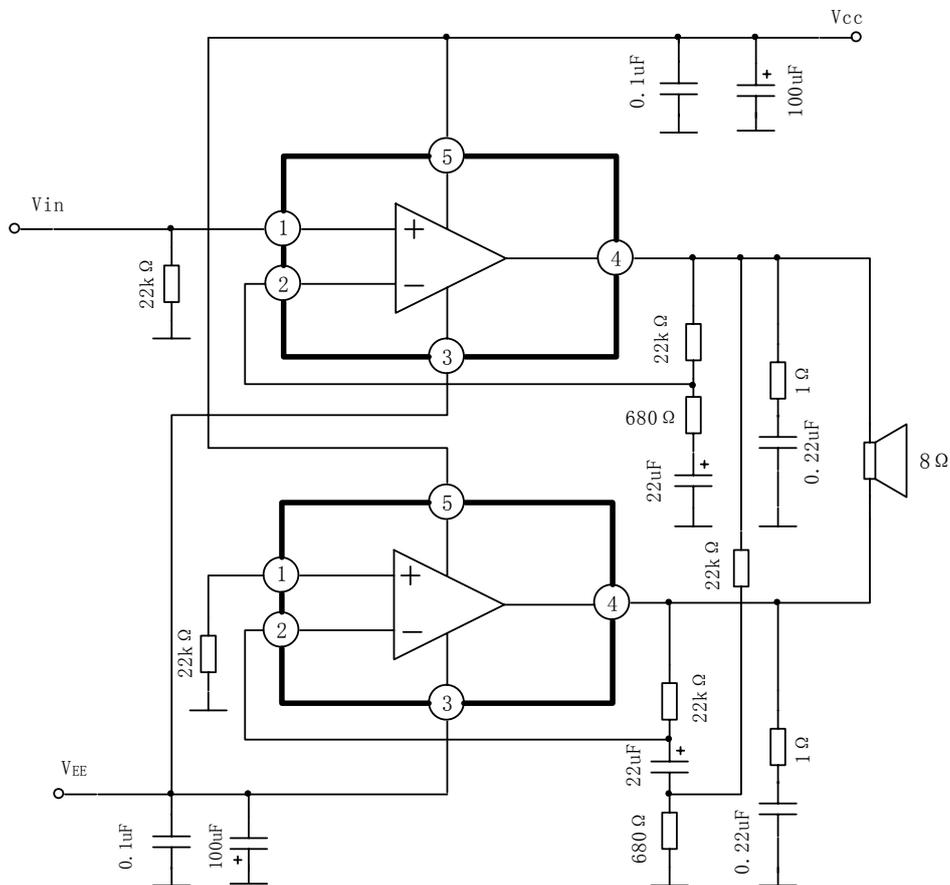
6.2 Single Supply Application Circuit



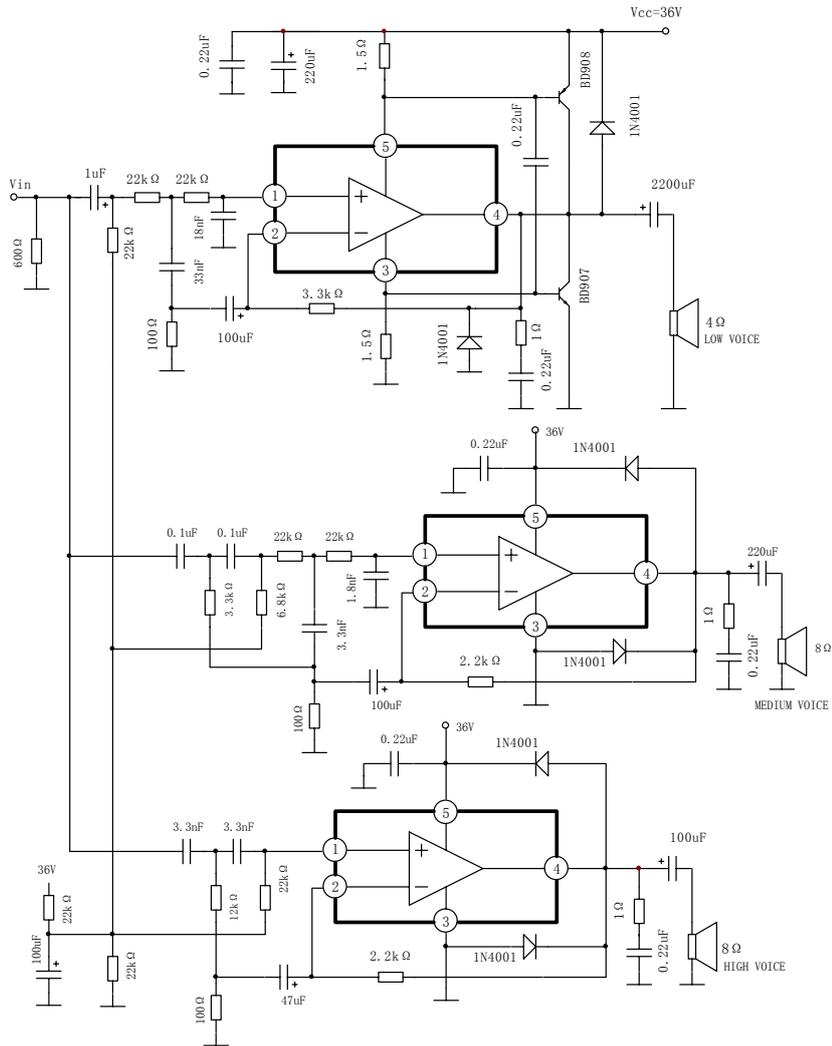
6.3 Power Driver Application Circuit



6.4 Bridge Amplifier with Split Power Supply ($V_{CC} = +16V, V_{EE} = -16V, P_O > 34W$)



6.5 3×60W Active Loudspeaker System



6.6 Note

- (1) The recommended supply voltage should not be higher than 44V.
- (2) Please refer to the power dissipation curve when making heat sink.

7.Package Dimensions

